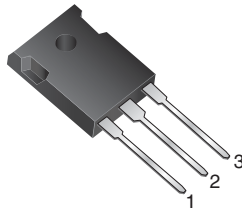
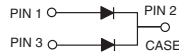


Dual Common Cathode Ultrafast Plastic Rectifier



TO-247AD (TO-3P)



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	30 A
V_{RRM}	50 V, 100 V, 150 V, 200 V
I_{FSM}	300 A
t_{rr}	25 ns
V_F at I_F	0.85 V
T_J max.	150 °C
Package	TO-247AD (TO-3P)
Diode variation	Common cathode

FEATURES

- Power pack
- Glass passivated pellet chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Molding compound meets UL 94V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	UG30APT	UG30BPT	UG30CPT	UG30DPT	UNIT
Max. repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Max. RMS voltage	V_{RMS}	35	70	105	140	V
Max. DC blocking voltage	V_{DC}	50	100	150	200	V
Max. average forward rectified current at $T_C = 120\text{ °C}$	$I_{F(AV)}$	30				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	300				A
Operating and storage temperature range	T_J, T_{STG}	-65 to +150				°C



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	UG30APT	UG30BPT	UG30CPT	UG30DPT	UNIT
Max. instantaneous forward voltage per diode	15 A	T _J = 100 °C	V _F	1.0				V
	30 A			1.15				
	10 A			0.85				
Max. DC reverse current at rated DC blocking voltage per diode			I _R	15				μA
				800				
Max. reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	25				ns
Max. reverse recovery time	I _F = 15 A, V _R = 30 V, dl/dt = 50 A/μs, I _{RR} = 10 % I _{RM}	T _J = 25 °C	t _{rr}	35				ns
		T _J = 100 °C		50				
Max. recovered stored charge	I _F = 15 A, V _R = 30 V, dl/dt = 50 A/μs, I _{RR} = 10 % I _{RM}	T _J = 25 °C	Q _{rr}	22				nC
		T _J = 100 °C		50				
Typical junction capacitance	4.0 V, 1 MHz		C _J	70				pF

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG30APT	UG30BPT	UG30CPT	UG30DPT	UNIT
Typical thermal resistance per diode ⁽¹⁾	R _{θJC}	2.0				°C/W

Note

⁽¹⁾ Thermal resistance from junction to case per diode mounted on heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-247AD	UG30DPT-E3/45	6.15	30	30/tube	Tube



RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

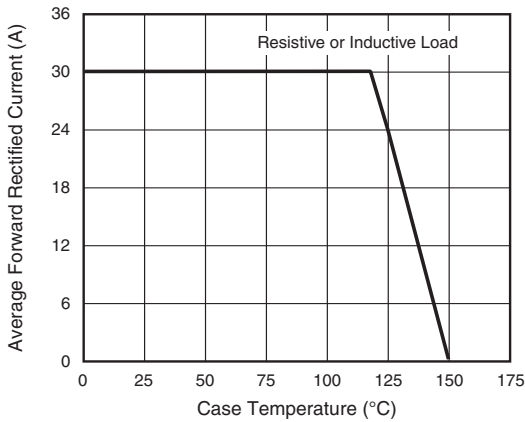


Fig. 1 - Max. Forward Current Derating Curve

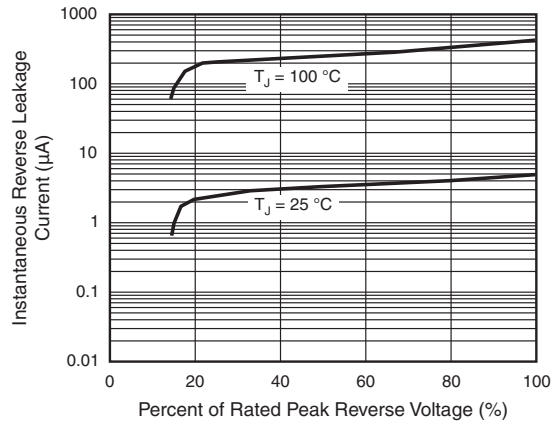


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

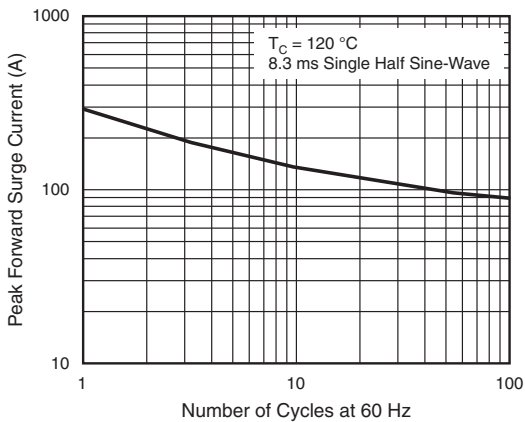


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

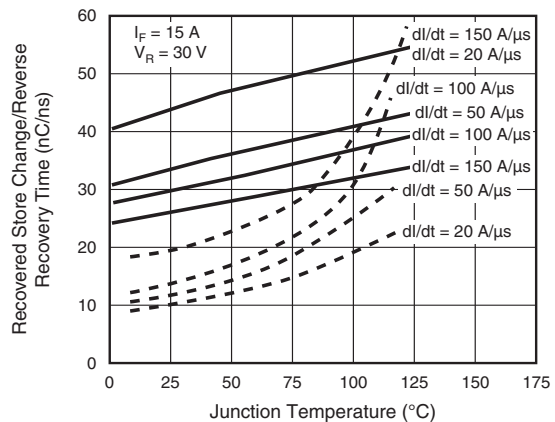


Fig. 5 - Reverse Switching Characteristics Per Diode

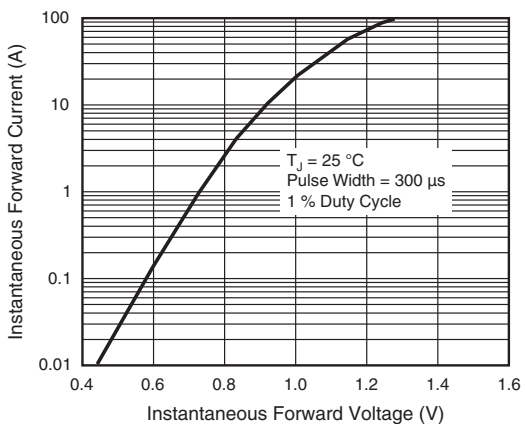


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

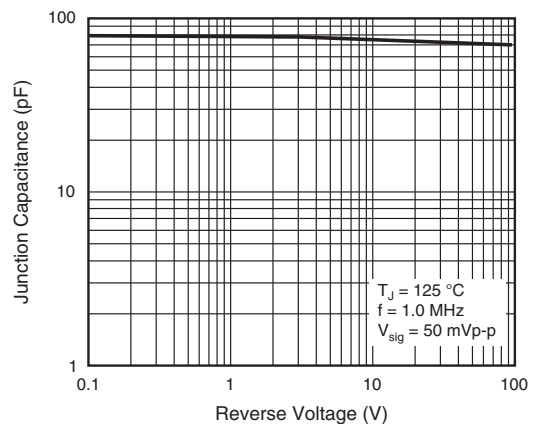


Fig. 6 - Typical Junction Capacitance Per Diode



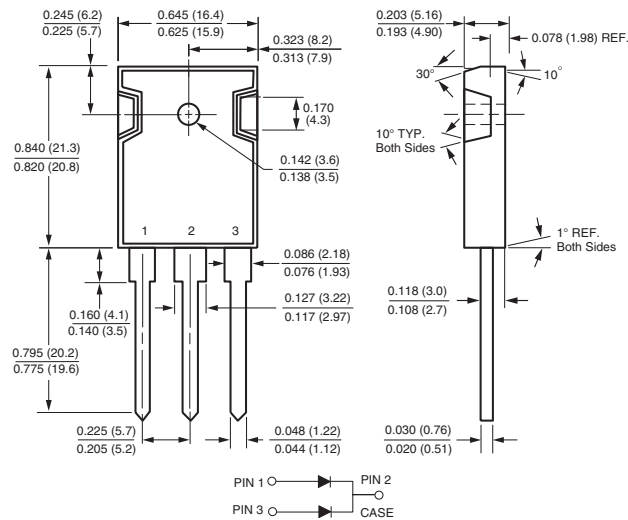
UG30APT-E3, UG30BPT-E3, UG30CPT-E3, UG30DPT-E3

www.vishay.com

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-247AD (TO-3P)





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